

# 74HCT00D

### 1. Functional Description

• Quad 2-Input NAND Gate

#### 2. General

The 74HCT00D is a high speed CMOS 2-INPUT NAND GATE fabricated with silicon gate C<sup>2</sup>MOS technology. It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

This device may be used as a level converter for interfacing TTL or NMOS to High Speed CMOS. The inputs are compatible with TTL, NMOS and CMOS output voltage levels.

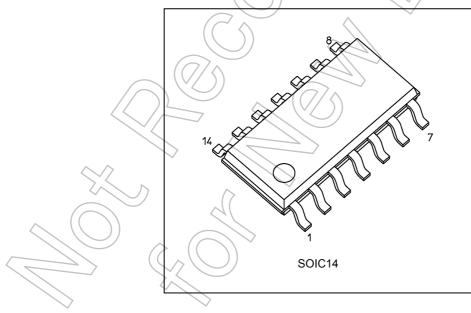
The internal circuit is composed of 3 stages including buffer output, which provide high noise immunity and stable output.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

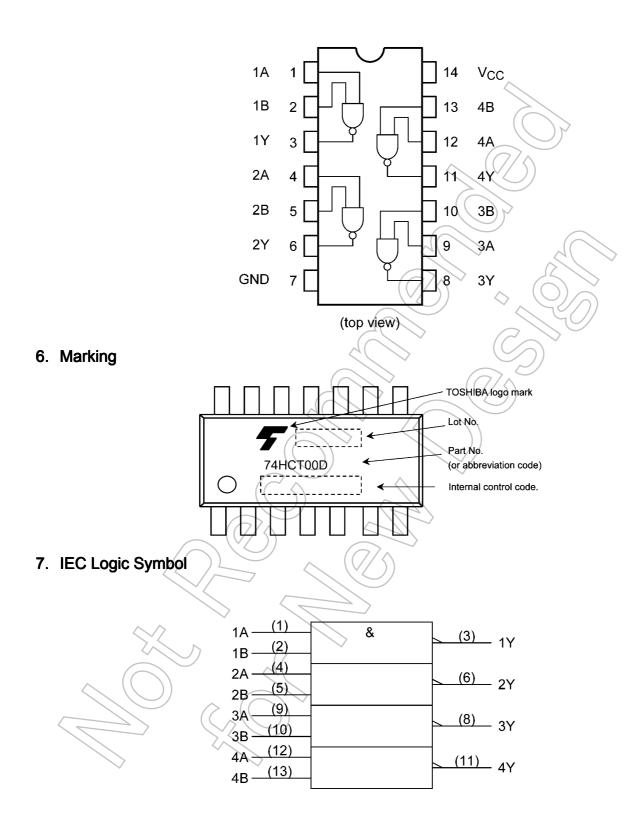
### 3. Features

- (1) High speed:  $t_{pd}$  = 10 ns (typ.) at  $V_{CC}$  = 5 V
- (2) Low power dissipation:  $I_{CC} = 1.0 \ \mu A \ (max) \ at \ T_a = 25 \ ^{\circ}C$
- (3) Compatible with TTL outputs:  $V_{IH} = 2.0 V (min)$
- $V_{\rm IL} = 0.8 \, \mathrm{V} \, (\mathrm{max})$
- (4) Wide interfacing ability: LSTTL, NMOS, CMOS
- (5) Balanced propagation delays:  $t_{PLH} \approx t_{PHL}$

#### 4. Packaging



### **TOSHIBA** 5. Pin Assignment



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#### 8. Truth Table

А	В	Y
L	L	Н
L	Н	Н
Н	L	Н
Н	Н	L

### 9. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	-0.5 to 7.0	V
Input voltage	V <sub>IN</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
Output voltage	V <sub>OUT</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
Input diode current	l <sub>IK</sub>	±20	mA
Output diode current	I <sub>ОК</sub>	±20	mA
Output current	I <sub>OUT</sub>	±25	mA
V <sub>CC</sub> /ground current	I <sub>CC</sub>	±50	mA
Power dissipation	PD	500	mW
Storage temperature	T <sub>stg</sub>	-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

### 10. Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	Vcc	4.5 to 5.5	V
Input voltage	VIN	0 to V <sub>CC</sub>	V
Output voltage	VOUT	0 to V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>	-40 to 85	°C
Input rise and fall times	t <sub>r</sub> ,t <sub>f</sub>	0 to 500	ns

Note: The operating ranges are required to ensure the normal operation of the device. Unused inputs must be tied to either  $V_{CC}$  or GND.

### **11. Electrical Characteristics**

### 11.1. DC Characteristics (Unless otherwise specified, $T_a = 25$ °C)

Characteristics	Symbol	Test Condition		V <sub>CC</sub> (V)	Min	Тур.	Max	Unit
High-level input voltage	V <sub>IH</sub>	_		4.5 to 5.5	2.0	—	—	V
Low-level input voltage	V <sub>IL</sub>	_		4.5 to 5.5	X		0.8	V
High-level output voltage	V <sub>OH</sub>	$V_{IN} = V_{IH}$ or $V_{IL}$	I <sub>OH</sub> = -20 μA	4.5	4.4	4.5	—	V
			I <sub>OH</sub> = -4 mA	4.5	4.18	4.31	—	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub>	I <sub>OL</sub> = 20 μA	4.5		0.0	0.1	V
			I <sub>OL</sub> = 4 mA	4.5	7	0.17	0.26	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	$\mathcal{I}$	_	±0.1	μA
Quiescent supply	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	> -	_	1.0	μA
current	I <sub>CCT</sub>	Per input: V <sub>IN</sub> = 0.5 V or		5.5	_	_	2.0	mA
		2.4 V Other input: V <sub>CC</sub> or GND	20	$\searrow$				

# 11.2. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Min	Max	Unit
High-level input voltage	V <sub>IH</sub>	- 20	4.5 to 5.5	2.0	_	V
Low-level input voltage	V <sub>IL</sub>	$- \langle \langle \rangle \rangle$	4.5 to 5.5	$\langle \rangle$	0.8	V
High-level output voltage	V <sub>OH</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{\Theta H} = -20 \ \mu \text{A}$	4.5	4.4	—	V
		І <sub>ОН</sub> = -4 mА	4.5	4.13	—	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> I <sub>OL</sub> = 20 μA	4.5	_	0.1	V
		$I_{OL} = 4 \text{ mA}$	4.5	_	0.33	]
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5	_	±1.0	μA
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5	_	10.0	μA
	Ісст	Per input: V <sub>IN</sub> = 0.5 V or 2.4 V	5.5	—	2.9	mA
		Other input: V <sub>CC</sub> or GND				

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### 11.3. AC Characteristics

(Unless otherwise specified,  $C_L = 15 \text{ pF}$ ,  $V_{CC} = 5 \text{ V}$ ,  $T_a = 25 \text{ °C}$ , Input:  $t_r = t_f = 6 \text{ ns}$ )

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Output transition time	t <sub>TLH</sub> ,t <sub>THL</sub>	—	_	4	8	ns
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>	—		10	20	

### 11.4. AC Characteristics

### (Unless otherwise specified, $C_L = 50 \text{ pF}$ , $T_a = 25 \text{ °C}$ , Input: $t_r = t_f = 6 \text{ ns}$ )

Characteristics	Symbol	Note	V <sub>CC</sub> (V)	Min	Тур.	Max	Unit
Output transition time	t <sub>TLH</sub> ,t <sub>THL</sub>		4.5	X FC	8	15	ns
			5.5		7	14	ns
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		4.5	Å	13	19	ns
			5.5	)	12	17	ns
Input capacitance	C <sub>IN</sub>		L	$\sim$ –	5	$\searrow$	pF
Power dissipation capacitance	C <sub>PD</sub>	(Note 1)		_	19	<u> </u>	pF

Note 1:  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.  $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/4$  (per gate)

### 11.5. AC Characteristics

### (Unless otherwise specified, $C_L = 50 pF$ , $T_a = -40$ to 85 °C, Input: $t_r = t_f = 6 ns$ )

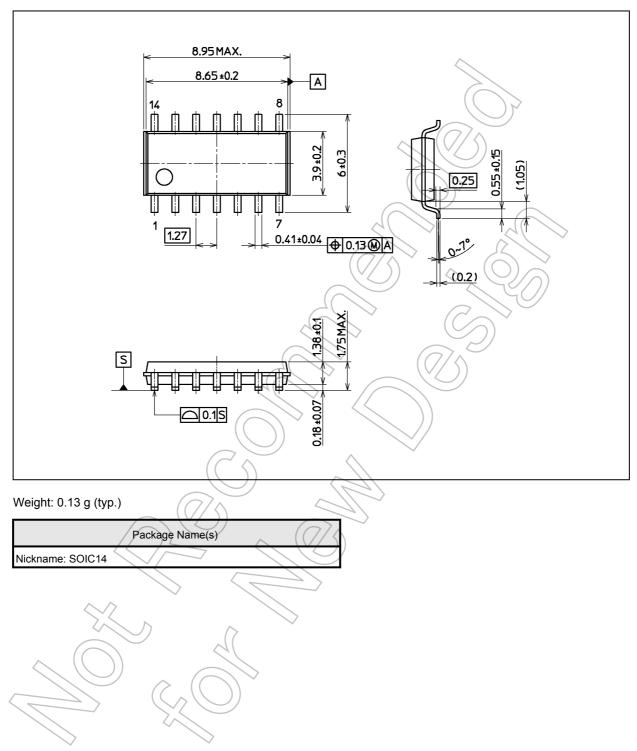
Characteristics	Symbol		V <sub>CC</sub> (V)	Min	Max	Unit
Output transition time	t <sub>tlh</sub> ,t <sub>thl</sub>		4.5	—	19	ns
			5.5	_	18	ns
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		4.5	_	24	ns
	$\mathcal{C}$	$\land$	5.5	_	21	ns



### **Package Dimensions**

74HCT00D

Unit: mm



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